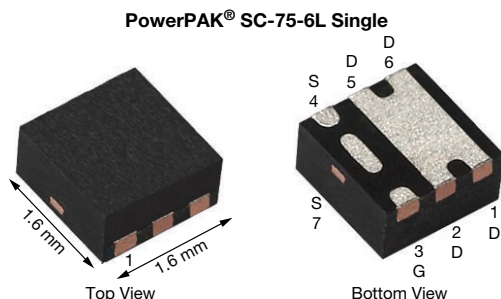


P-Channel 12 V (D-S) MOSFET



Marking code: BO

PRODUCT SUMMARY	
V_{DS} (V)	-12
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.0255
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -3.7$ V	0.0280
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -2.5$ V	0.0360
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -1.8$ V	0.0600
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -1.5$ V	0.1150
Q_g typ. (nC)	13.4
I_D (A) ^a	9
Configuration	Single

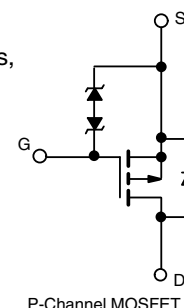
FEATURES

- TrenchFET[®] power MOSFET
- Thermally enhanced PowerPAK[®] SC-75 package
 - Small footprint area
 - Low on-resistance
- Typical ESD performance 2500 V
- 100 % R_g tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Portable devices such as smart phones, tablet PCs, and mobile computing
 - Battery switch
 - Load switch
 - Power management



P-Channel MOSFET

ORDERING INFORMATION

Package	PowerPAK SC-75
Lead (Pb)-free and halogen-free	SiB441EDK-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V_{DS}	-12	V
Gate-source voltage	V_{GS}	± 8	V
Continuous drain current ($T_J = 150$ °C)	$T_C = 25$ °C	-9 ^a	A
	$T_C = 70$ °C	-9 ^a	
	$T_A = 25$ °C	-8.3 ^{b, c}	
	$T_A = 70$ °C	-6.6 ^{b, c}	
Pulsed drain current ($t = 300$ μ s)	I_{DM}	-40	A
Continuous source-drain diode current	$T_C = 25$ °C	-9 ^a	A
	$T_A = 25$ °C	-2 ^{b, c}	
Maximum power dissipation	$T_C = 25$ °C	13	W
	$T_C = 70$ °C	8.4	
	$T_A = 25$ °C	2.4 ^{b, c}	
	$T_A = 70$ °C	1.6 ^{b, c}	
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) ^{d, e}		260	°C

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^{b, f}	R_{thJA}	41	51	°C/W
Maximum junction-to-case (drain)	R_{thJC}	7.5	9.5	

Notes

- Package limited
- Surface mounted on 1" x 1" FR4 board
- $t = 5$ s
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- Maximum under steady state conditions is 105 °C/W



SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = -250 μA	-12	-	-	V
V _{DS} temperature coefficient	ΔV _{DS} /T _J	I _D = -250 μA	-	-5	-	mV/°C
V _{GS(th)} temperature coefficient	ΔV _{GS(th)} /T _J		-	2.7	-	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-0.4	-	-0.9	V
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V	-	-	± 4	μA
		V _{DS} = 0 V, V _{GS} = ± 4.5 V	-	-	± 1	
Zero gate voltage drain current	I _{DSS}	V _{DS} = -12 V, V _{GS} = 0 V	-	-	-1	
		V _{DS} = -12 V, V _{GS} = 0 V, T _J = 55 °C	-	-	-10	
On-state drain current ^a	I _{D(on)}	V _{DS} ≤ -5 V, V _{GS} = -4.5 V	-15	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5 V, I _D = -4 A	-	0.0210	0.0255	Ω
		V _{GS} = -3.7 V, I _D = -4 A	-	0.0230	0.0280	
		V _{GS} = -2.5 V, I _D = -2 A	-	0.0290	0.0360	
		V _{GS} = -1.8 V, I _D = -2 A	-	0.0420	0.0600	
		V _{GS} = -1.5 V, I _D = -0.5 A	-	0.0570	0.1150	
Forward transconductance ^a	g _{fs}	V _{DS} = -6 V, I _D = -4 A	-	17	-	S
Dynamic ^b						
Input capacitance	C _{iss}	V _{DS} = -6 V, V _{GS} = 0 V, f = 1 MHz	-	1180	-	pF
Output capacitance	C _{oss}		-	265	-	
Reverse transfer capacitance	C _{rss}		-	250	-	
Total gate charge	Q _g	V _{DS} = -6 V, V _{GS} = -8 V, I _D = -2.1 A	-	22.1	33	nC
		V _{DS} = -6 V, V _{GS} = -4.5 V, I _D = -2.1 A	-	13.4	20	
Q _{gs}	-		1.6	-		
Q _{gd}	-		3.4	-		
Gate resistance	R _g	f = 1 MHz	2.2	11	22	Ω
Turn-on delay time	t _{d(on)}	V _{DD} = -6 V, R _L = 2.7 Ω I _D ≅ -2.2 A, V _{GEN} = -4.5 V, R _g = 1 Ω	-	22	45	ns
Rise time	t _r		-	42	85	
Turn-off delay time	t _{d(off)}		-	60	120	
Fall time	t _f		-	50	100	
Turn-on delay time	t _{d(on)}	V _{DD} = -6 V, R _L = 2.7 Ω I _D ≅ -2.2 A, V _{GEN} = -8 V, R _g = 1 Ω	-	7	15	
Rise time	t _r		-	10	20	
Turn-off delay time	t _{d(off)}		-	60	120	
Fall time	t _f		-	52	100	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I _S	T _C = 25 °C	-	-	-9	A
Pulse diode forward current	I _{SM}		-	-	-40	
Body diode voltage	V _{SD}	I _S = -2.2 A, V _{GS} = 0 V	-	-0.85	-1.2	V
Body diode reverse recovery time	t _{rr}	I _F = -2.2 A, di/dt = 100 A/μs, T _J = 25 °C	-	30	60	ns
Body diode reverse recovery charge	Q _{rr}		-	12	25	nC
Reverse recovery fall time	t _a		-	9	-	ns
Reverse recovery rise time	t _b		-	11	-	

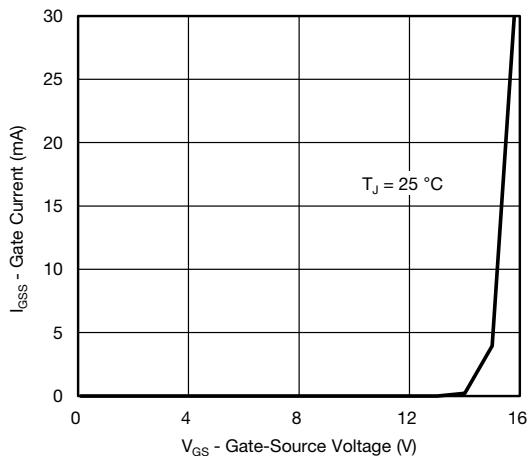
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing

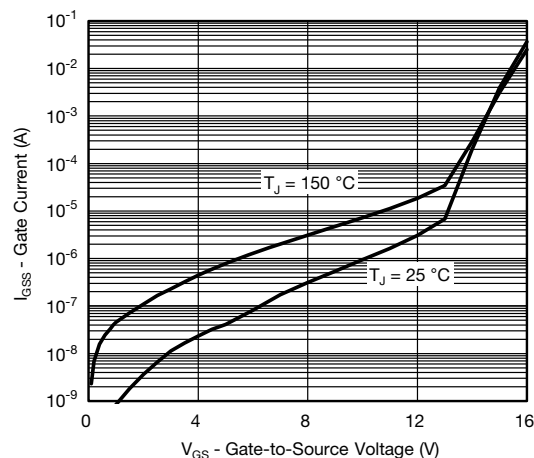
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



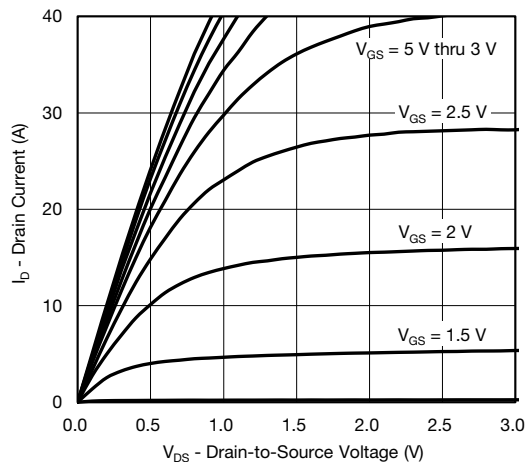
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



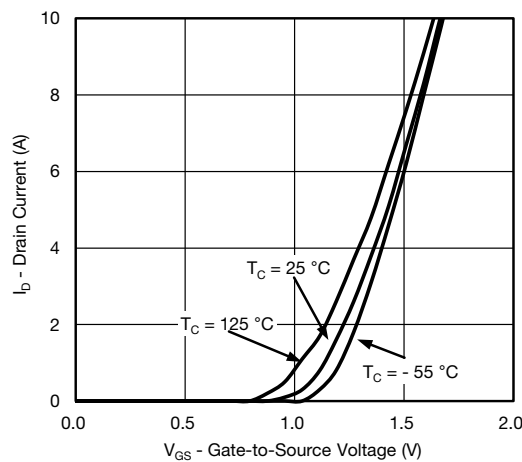
Gate Current vs. Gate-Source Voltage



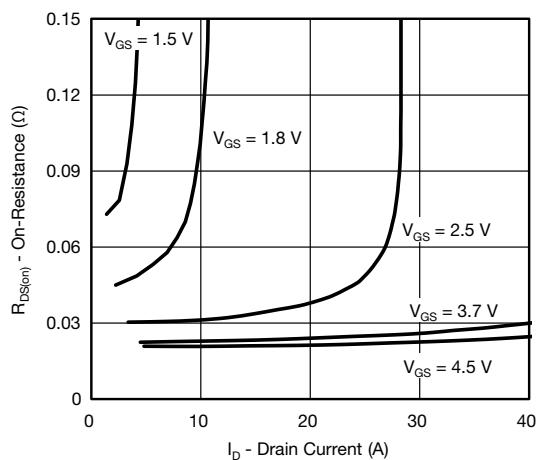
Gate Current vs. Gate-Source Voltage



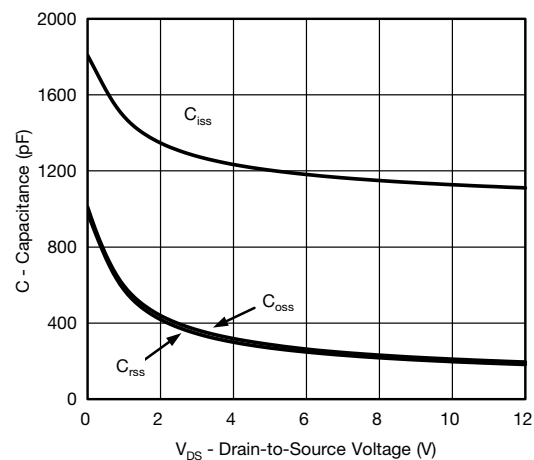
Output Characteristics



Transfer Characteristics



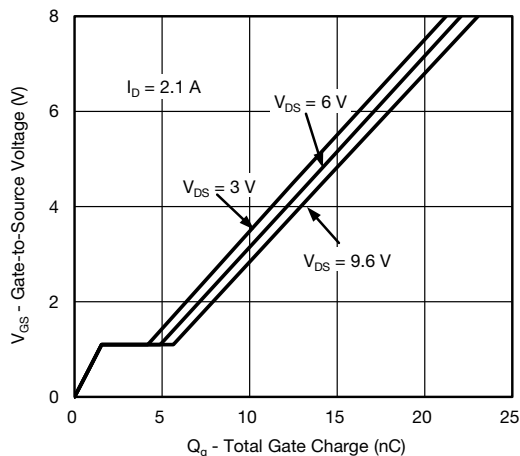
On-Resistance vs. Drain Current



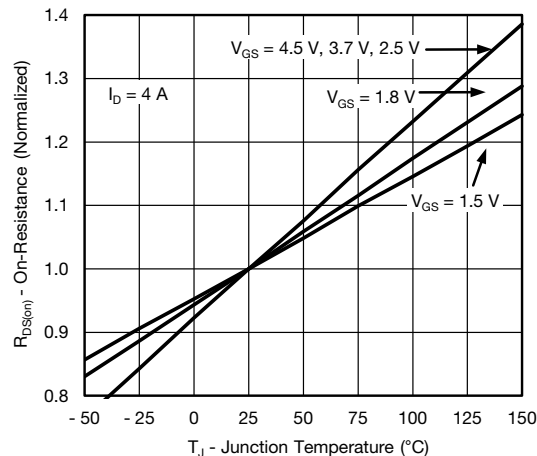
Capacitance



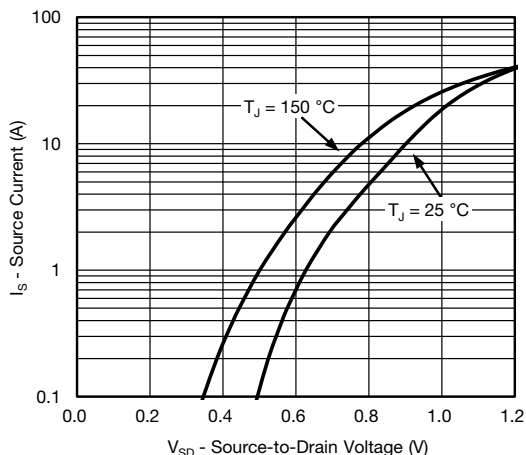
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



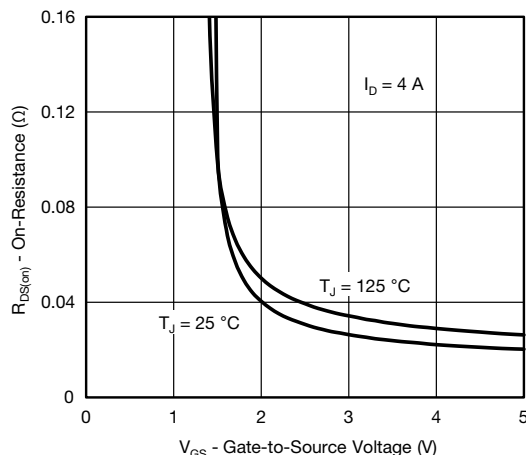
Gate Charge



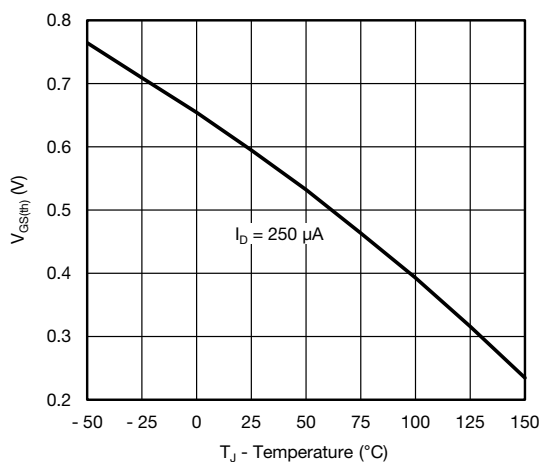
On-Resistance vs. Junction Temperature



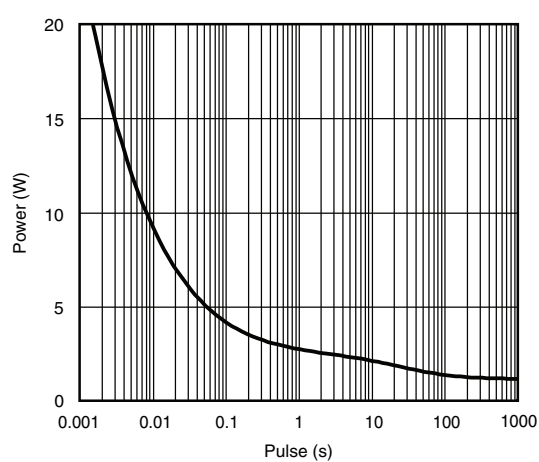
Source-Drain Diode Forward Voltage



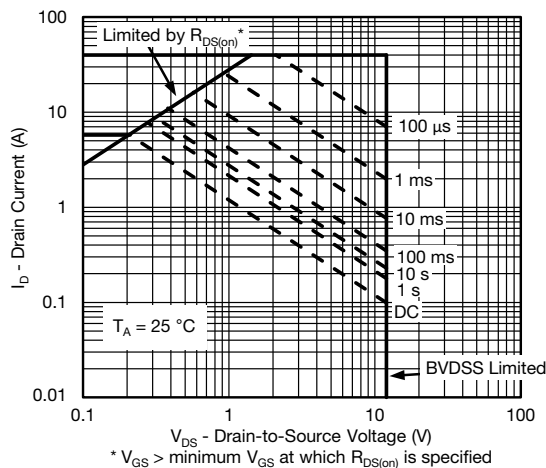
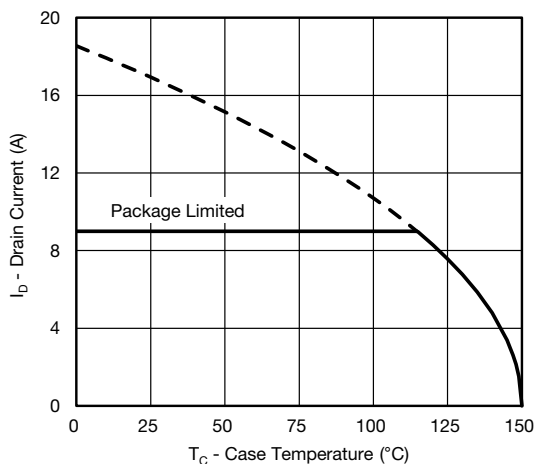
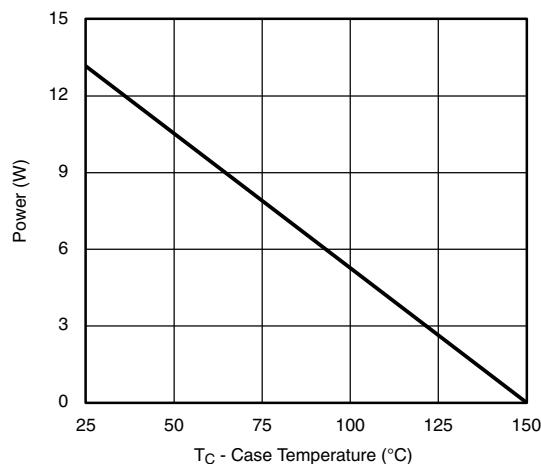
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



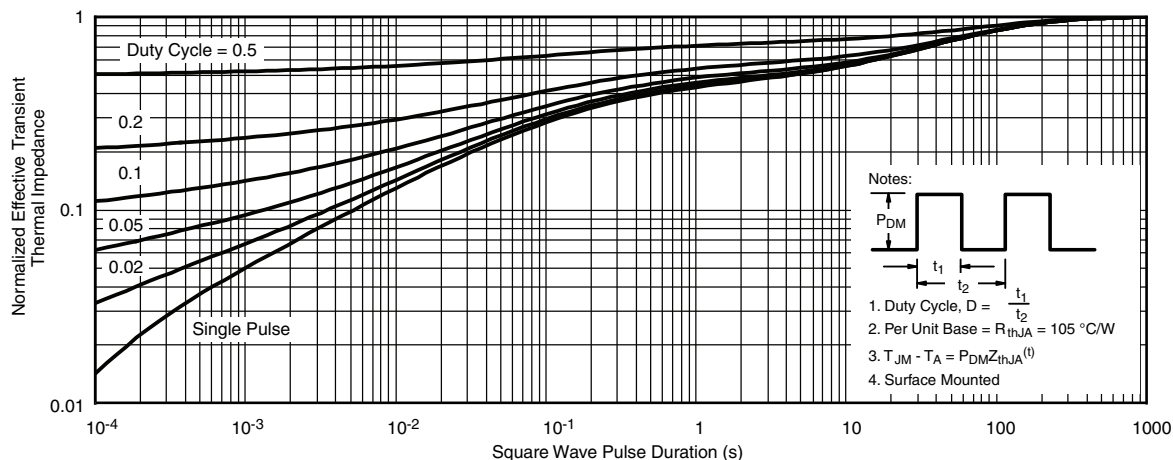
Single Pulse Power, Junction-to-Ambient

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Safe Operating Area, Junction-to-Ambient

Current Derating ^a

Power Derating
Note

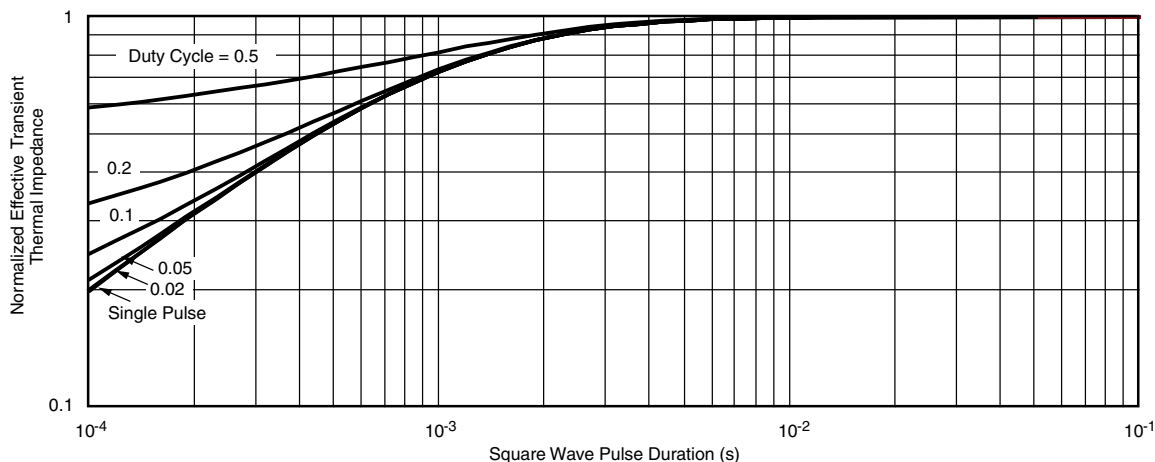
- The power dissipation P_D is based on $T_J \text{ max.} = 150^\circ\text{C}$, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

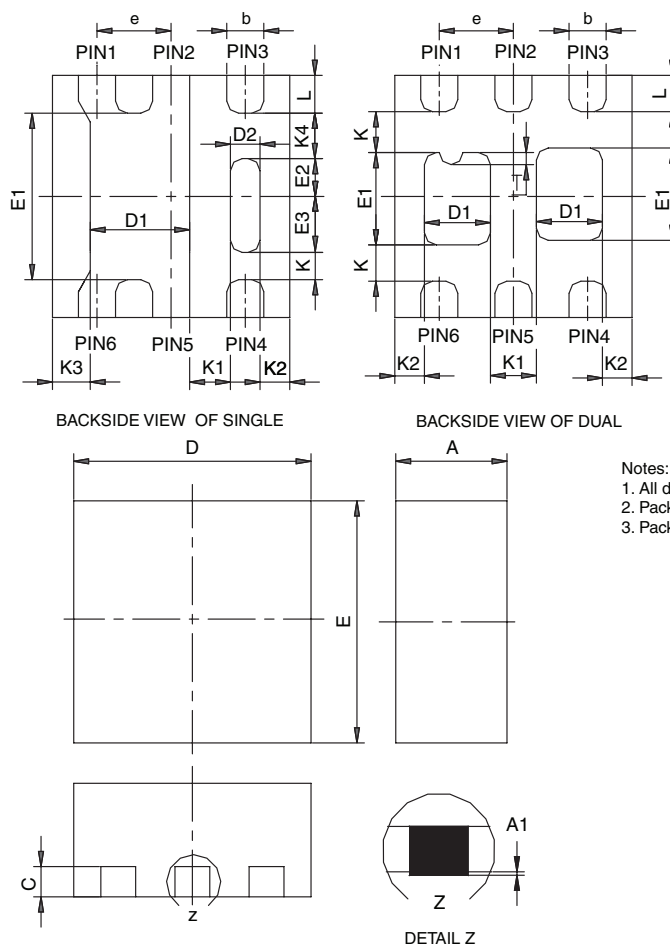


Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62821.



PowerPAK® SC75-6L



- Notes:
1. All dimensions are in millimeters
 2. Package outline exclusive of mold flash and metal burr
 3. Package outline inclusive of plating

DIM	SINGLE PAD						DUAL PAD					
	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
A	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.18	0.25	0.33	0.007	0.010	0.013	0.18	0.25	0.33	0.007	0.010	0.013
C	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
D1	0.57	0.67	0.77	0.022	0.026	0.030	0.34	0.44	0.54	0.013	0.017	0.021
D2	0.10	0.20	0.30	0.004	0.008	0.012						
E	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
E1	1.00	1.10	1.20	0.039	0.043	0.047	0.51	0.61	0.71	0.020	0.024	0.028
E2	0.20	0.25	0.30	0.008	0.010	0.012						
E3	0.32	0.37	0.42	0.013	0.015	0.017						
e	0.50 BSC			0.020 BSC			0.50 BSC			0.020 BSC		
K	0.180 TYP			0.007 TYP			0.245 TYP			0.010 TYP		
K1	0.275 TYP			0.011 TYP			0.320 TYP			0.013 TYP		
K2	0.200 TYP			0.008 TYP			0.200 BSC			0.008 TYP		
K3	0.255 TYP			0.010 TYP								
K4	0.300 TYP			0.012 TYP								
L	0.15	0.25	0.35	0.006	0.010	0.014	0.15	0.25	0.35	0.006	0.010	0.014
T							0.03	0.08	0.13	0.001	0.003	0.005

ECN: C-07431 – Rev. C, 06-Aug-07
DWG: 5935

Technical drawing of a mechanical part, showing dimensions in inches (in) and millimeters (mm) in parentheses. The drawing includes a central rectangular feature with a circular hole, and two smaller rectangular features on the right side. The dimensions are as follows:

- Overall width: 2.000 (0.079)
- Overall height: 2.000 (0.079)
- Top horizontal dimension: 1.250 (0.049)
- Top horizontal dimension: 0.250 (0.01)
- Top horizontal dimension: 0.500 (0.02)
- Top horizontal dimension: 0.400 (0.016)
- Top horizontal dimension: 0.370 (0.015)
- Top horizontal dimension: 0.620 (0.024)
- Top horizontal dimension: 0.200 (0.008)
- Top horizontal dimension: 0.250 (0.01)
- Top horizontal dimension: 0.670 (0.026)
- Top horizontal dimension: 0.545 (0.021)
- Top horizontal dimension: 0.300 (0.012)
- Top horizontal dimension: 0.300 (0.012)
- Top horizontal dimension: 0.300 (0.012)
- Top horizontal dimension: 0.180 (0.007)
- Top horizontal dimension: 0.300 (0.012)
- Top horizontal dimension: 0.100 (0.004)
- Top horizontal dimension: 0.250 (0.01)
- Top horizontal dimension: 0.300 (0.012)
- Top horizontal dimension: 1.100 (0.043)
- Top horizontal dimension: 1.700 (0.067)

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